

RL6

High Brightness LED

An Overview

OSRAM Opto Semiconductors GmbH

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- 📁 Fast Changing World Of Opto Electronics
- 📁 InGaAIP Thin Film Technology
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Products of OSRAM Opto Semiconductors

Visible LED's	Infrared/HPL	OLED
<ul style="list-style-type: none"> TOPLED High Flux LED Compact Light Source Intelligent Displays 	<ul style="list-style-type: none"> IR-SMT Dual Inline Inter-rupter High Power Laser 	<ul style="list-style-type: none"> OLED for Mobile Phone OLED for Automot. Bendable OLED Multi-Color OLED

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The Innovation Sequences for Artificial Light Sources Become Shorter

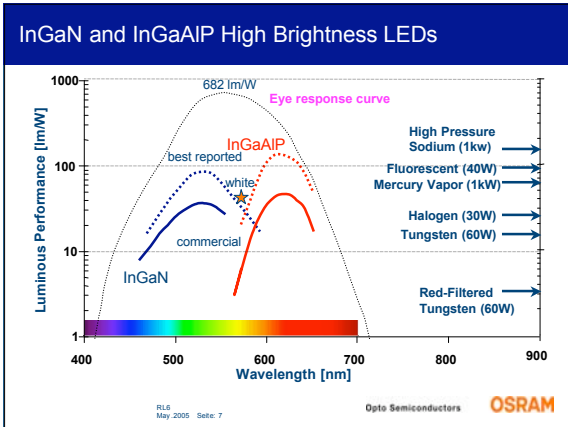
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Dramatic Brightness Evolution of LEDs in the Past-What's going on?

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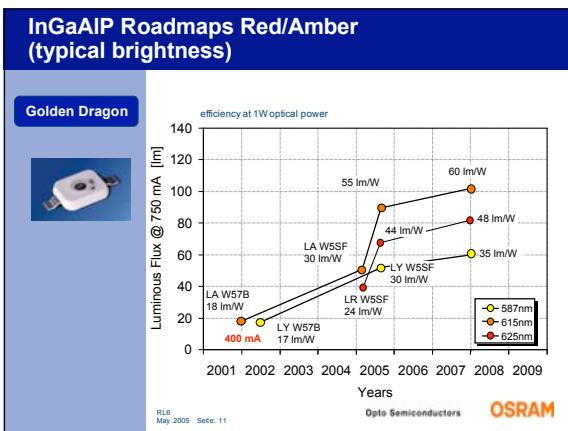
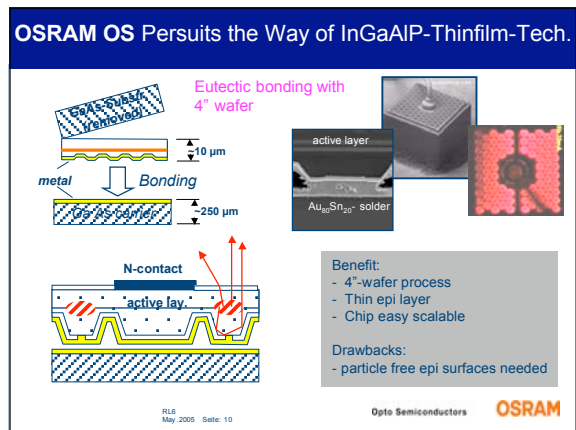
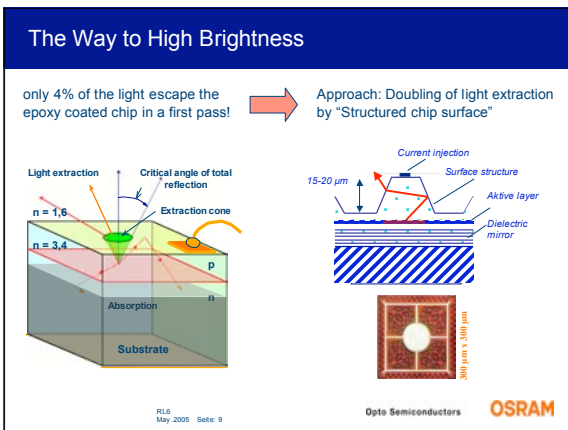
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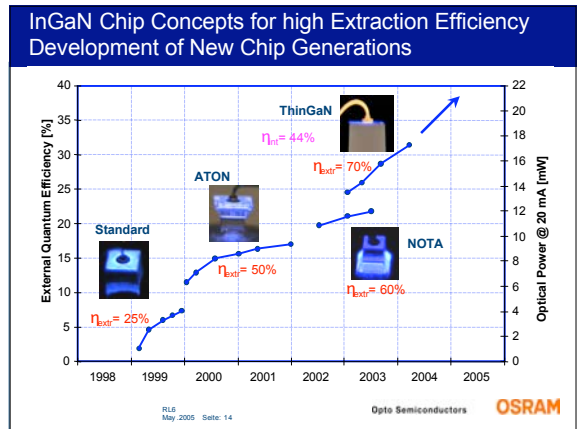
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InGaN Chip Technology on SiC Substrates

InGaN-Chip-Design

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Process Flow and Advantage of ThinGaN - OSRAM's Proprietary InGaN- High Brightness Technology

Process Flow:

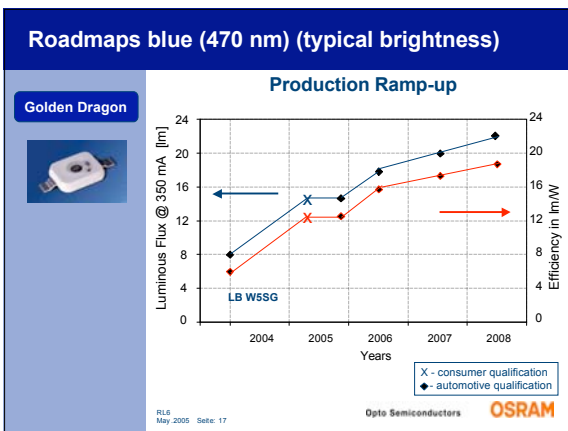
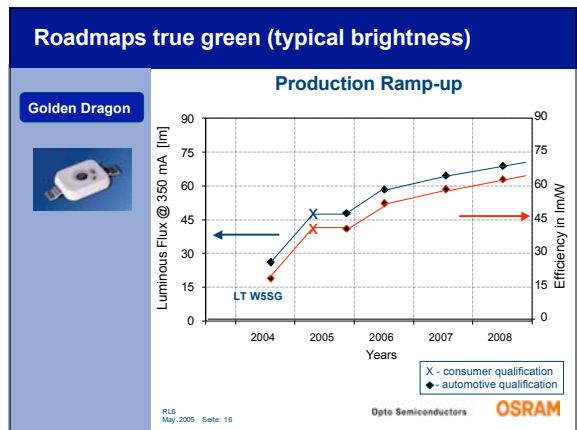
- epitaxy
- metallization
- bonding on carrier
- laser epi liftoff
- contacts
- chip dicing

Advantage of ThinGaN vs. ATON:

ATON	ThinGaN
• high efficiency	• Lambertian emission
• small chip size	• scalable
• low substrate costs	• low R_s
• easy mounting	• on chip conversion for white

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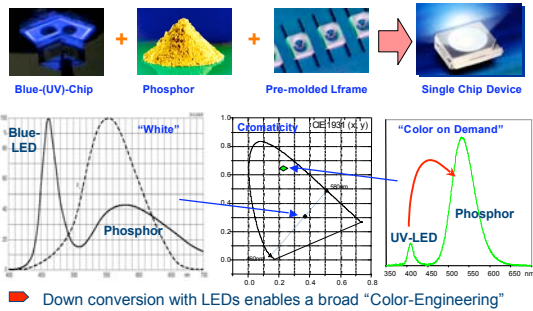
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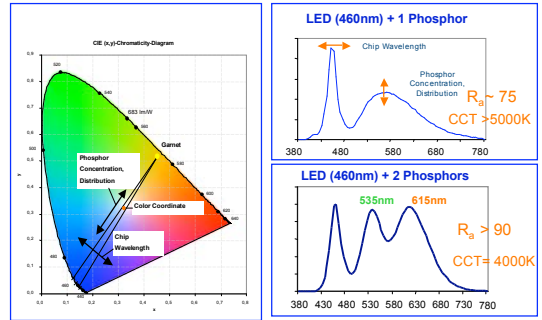
The Way from Blue (or UV) to Unsaturated Colors and White through Down Conversion



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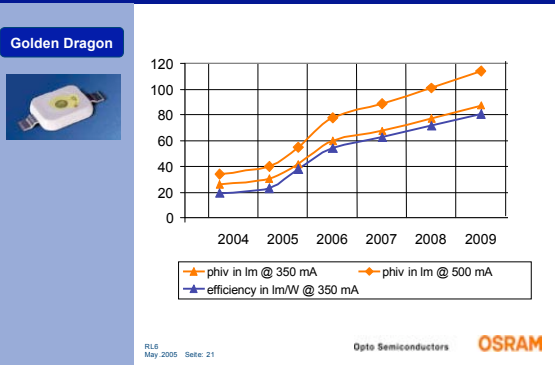
CRI Improvement of Blue Chip Based White LED



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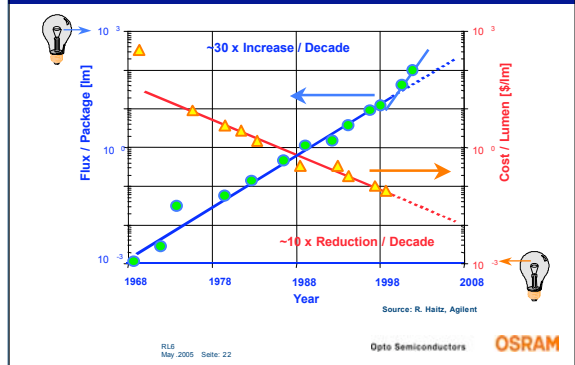
Roadmaps white (typical brightness)



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Haitz's Law for LED Flux and Costs per Lumen



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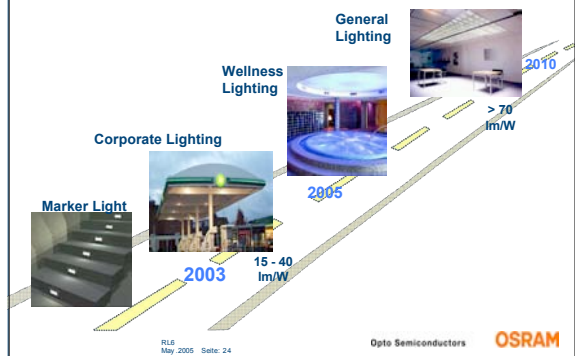
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Roadmap for Solid State Lighting



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LEDs "Bridge" Time and Space



A red beam stretches along the Stone Bridge across the River Danube. It provides a visual link between the two banks and at the same time highlights the historical development of Regensburg and one of city's oldest structures. Osram Opto Semiconductors is supporting Regensburg with an unusual lighting installation in its application to be named the City of Culture 2010... with 21,900 LEDs

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Signage



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Mood Lighting Innovation Award – Light&Building 2004



Prize for Innovation
in Architecture
and Technical Systems

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Theater Lighting



Floorlighting



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White LEDs for Surface Lighting and Room Lighting



The four exclusive fixtures, each one a metre square in size, combine to provide an unusually homogenous source of lighting above the conference table.

Each fixture is made up of 128 glass-mounted LINEARlight Modules and combines the luminosity of 4096 white LEDs. The luminaires feature a sandwich-layout and are based on a perforated and insulated metal plate onto which the LED modules are mounted.

From underneath they resemble a grid made up of dots of light on a dark background. Just as required for this lighting concept, the LED modules deliver cold, white light with a colour reproduction index of Ra = 80 and can achieve colour temperatures between 5250 and 6250 K.

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applications DRAGON

Reading light
Desk luminaries



Furniture and display cases
shop lighting
facade illumination



Mobile light



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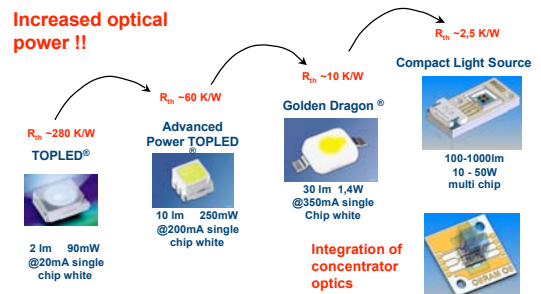
Approaches for Further Improvements of LED Quantum Efficiencies

- Improvements of chip materials and structures (internal Q.E.)**
 - reduction of defects and impurities
 - dedicated incorporation of dopants and profiles
 - laser like resonant structures
- New chip designs (extraction efficiencies)**
 - chip shaping by simulation
 - chip surfaces by simulation
 - photonic bandgap structures
- New package designs (light utilization and electrical losses)**
 - reduction of series resistance
 - improvement of thermal contacts
 - reduction of absorption losses
 - increase of conversion efficiencies
 - encapsulation materials with high refractive index

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Development of Innovative Power-LED Packages



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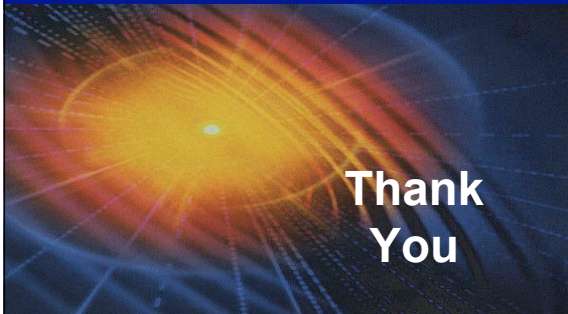
Summary

- LEDs have clear advantages in lighting applications where dedicated colors are required.
- LEDs will increasingly be used for low power white lighting applications accordingly to their brightness evolution.
- LED lamps will be far more expensive (lumen-wise) than all other conventional light sources for at least one decade.
- The expensive LED lamp must pay for itself through lifetime, maintenance savings, high degree of freedom for design and color management.

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RL6, May 2005



**Thank
You**

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